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FDC5614P

60V P-Channel Logic Level PowerTrench[®] MOSFET

General Description

This 60V P-Channel MOSFET uses Fairchild's high voltage PowerTrench process. It has been optimized for power management applications.

Applications

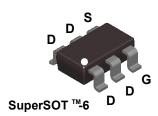
- DC-DC converters
- Load switch
- Power management

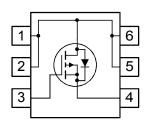
Features

$$R_{DS(ON)} = 0.105 \Omega @ V_{GS} = -10 V$$

 $R_{DS(ON)} = 0.135 \Omega @ V_{GS} = -4.5 V$

- Fast switching speed
- High performance trench technology for extremely low $R_{\text{DS}(\text{ON})}$





Absolute Maximum Ratings TA=25°C unless otherwise noted

Symbol	Parameter		Ratings	Units
V _{DSS}	Drain-Source Voltage		-60	V
V _{GSS}	Gate-Source Voltage		±20	V
ID	Drain Current – Continuous	(Note 1a)	-3	A
	- Pulsed		-20	
P _D	Maximum Power Dissipation	(Note 1a)	1.6	W
		(Note 1b)	0.8	
T _J , T _{STG}	Operating and Storage Junction Temperatu	ire Range	-55 to +150	°C
Therma	I Characteristics			
$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient	(Note 1a)	78	°C/W
R _{eJC}	Thermal Resistance, Junction-to-Case	(Note 1)	30	°C/W

Package Marking and Ordering Information

Device Marking	Device	Reel Size	Tape width	Quantity
.564	FDC5614P	7"	8mm	3000 units

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FDC5614P

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Symbol	Parameter	Test Conditions	Min	Тур	Мах	Units
Off Char	acteristics					
BV _{DSS}	Drain–Source Breakdown Voltage	V_{GS} = 0 V, I_{D} = -250 μ A	-60			V
<u>ΔBV_{DSS}</u> ΔT _J	Breakdown Voltage Temperature Coefficient	$I_D = -250 \ \mu$ A, Referenced to 25° C		-49		mV/°C
DSS	Zero Gate Voltage Drain Current	$V_{DS} = -48 \text{ V}, V_{GS} = 0 \text{ V}$			-1	μA
GSSF	Gate–Body Leakage, Forward	$V_{GS} = 20V, \qquad V_{DS} = 0 V$			100	nA
GSSR	Gate–Body Leakage, Reverse	V _{GS} = -20 V V _{DS} = 0 V			-100	nA
On Char	acteristics (Note 2)					
V _{GS(th)}	Gate Threshold Voltage	$V_{DS} = V_{GS}, I_D = -250 \ \mu A$	-1	-1.6	-3	V
<u>ΔV_{GS(th)}</u> ΔT _J	Gate Threshold Voltage Temperature Coefficient	I_D = -250 µA,Referenced to 25°C		4		mV/°C
R _{DS(on)}	Static Drain–Source On–Resistance	$V_{GS} = -10 \text{ V}, I_D = -3 \text{ A}$ $V_{GS} = -4.5 \text{ V}, I_D = -2.7 \text{ A}$ $V_{GS} = -10 \text{ V}, I_D = -3 \text{ A} \text{ T}_1 = 125^{\circ}\text{C}$		82 105 130	105 135 190	mΩ
D(on)	On-State Drain Current	$V_{GS} = -10 \text{ V}, \text{ I}_{D} = -3 \text{ A } \text{T}_{J} = 125^{\circ}\text{C}$ $V_{GS} = -10 \text{ V}, V_{DS} = -5 \text{ V}$	-20			Α
9 _{FS}	Forward Transconductance	$V_{DS} = -5 V$, $I_{D} = -3 A$		8		S
Dynamic	Characteristics					
C _{iss}	Input Capacitance	$V_{DS} = -30 V$, $V_{GS} = 0 V$,		759		pF
Coss	Output Capacitance	f = 1.0 MHz		90		pF
C _{rss}	Reverse Transfer Capacitance			39		pF
Switchin	g Characteristics (Note 2)					
d(on)	Turn–On Delay Time	$V_{DD} = -30 V$, $I_D = -1 A$,		7	14	ns
r r	Turn–On Rise Time	$V_{GS} = -10 \text{ V}, \qquad R_{GEN} = 6 \Omega$		10	20	ns
d(off)	Turn–Off Delay Time			19	34	ns
l _f	Turn–Off Fall Time			12	22	ns
Qg	Total Gate Charge	$V_{\rm DS} = -30V$, $I_{\rm D} = -3.0$ A,		15	24	nC
Q _{gs}	Gate–Source Charge	V _{GS} = -10 V		2.5		nC
Q _{gd}	Gate–Drain Charge			3.0		nC
Drain-S	ource Diode Characteristics	and Maximum Ratings				
s	Maximum Continuous Drain-Source				-1.3	Α
V _{SD}	Drain–Source Diode Forward Voltage	$V_{GS} = 0 V$, $I_S = -1.3 A$ (Note 2)		-0.8	-1.2	V

R_{6JA} is the sum of the junction-to-case and case-to-ambient resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. R_{6JC} is guaranteed by design while R_{6CA} is determined by the user's board design.

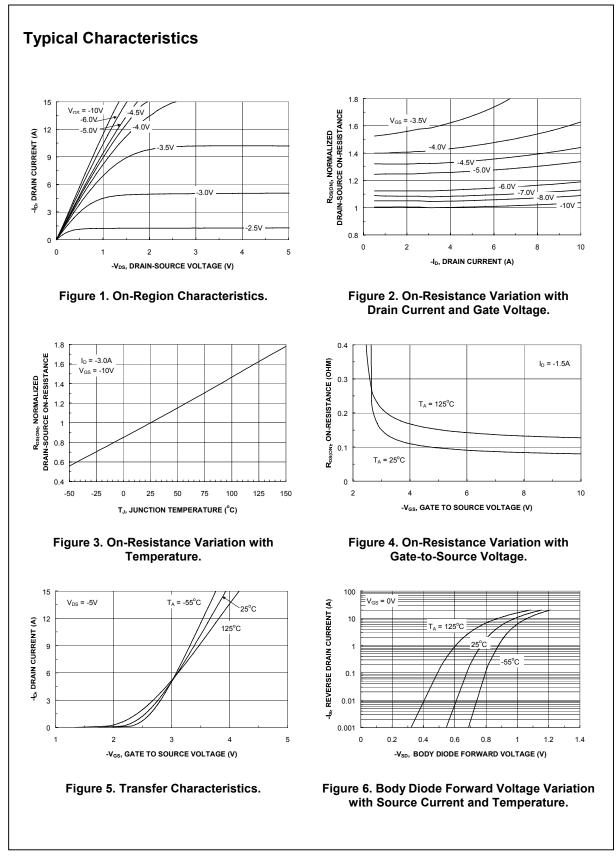
a. 78°C/W when mounted on a 1in² pad of 2oz copper on FR-4 board.

b. $156^{\circ}C/W$ when mounted on a minimum pad.

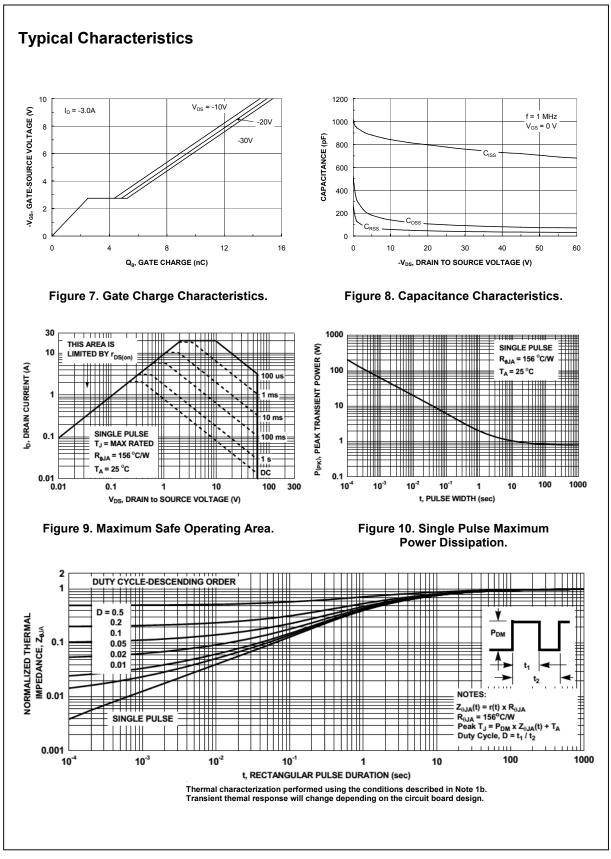
2. Pulse Test: Pulse Width \leq 300 $\mu s,$ Duty Cycle \leq 2.0%

FDC5614P Rev. 1.4

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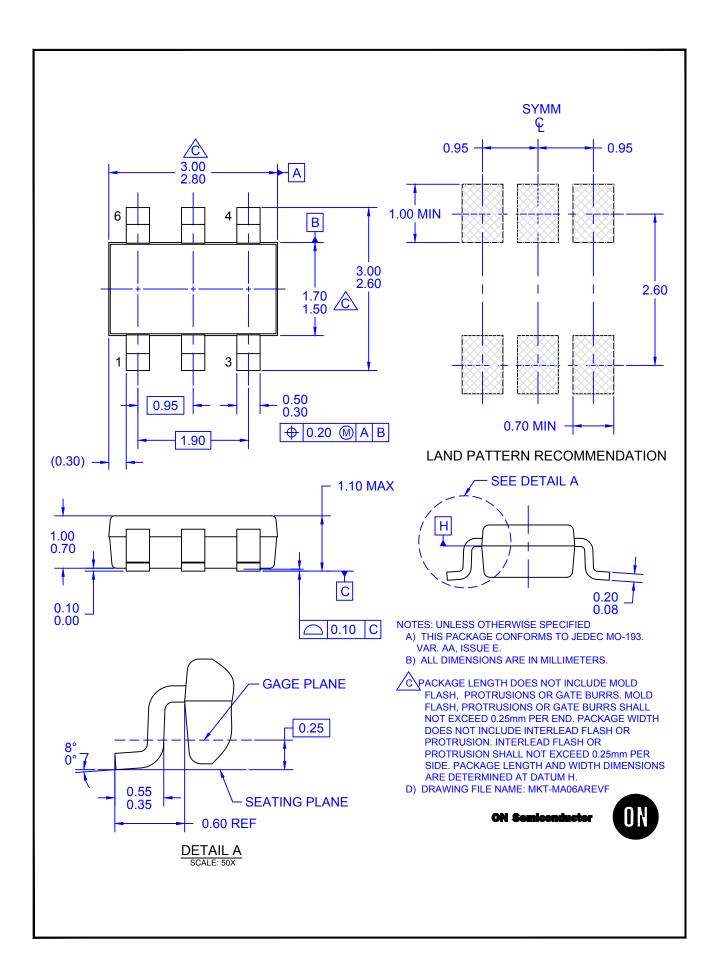


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